

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re U.S. Patent Application of:

INVENTORS: Fletcher et al.

SERIAL NO.: To be assigned ART UNIT:

FILED: herewith EXAMINER:

TITLE: PIN Detector Apparatus and Method of Fabrication

ATTORNEY DOCKET NO.: 901.0120.U1(US)

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Dear Sir:

Pursuant to Sections 609 and 707.05(b) of the MPEP and 37 CFR 1.97-1.99, copies are herewith submitted of documents which may be pertinent to the invention as claimed in the above-identified application. The attached form PTO-1449 lists these documents.

The citation of these documents should not be construed as a representation that a thorough search has been made, or that other, more pertinent material is not available.

Respectfully submitted,



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**INFORMATION DISCLOSURE
CITATION FORM FOR
PATENT APPLICATION
(FORM PTO-1449)
(Substitute)**

Docket No.: 901.0120.U1(US)

Serial No.: To be assigned

Applicant(s): Fletcher et al..

Filing Date: herewith

Group: N/A

U.S. PATENT DOCUMENTS

Examiner Initials	Document Number (Number-Kind Code)	Publication Date (MM-DD-YYYY)	Name of Patentee or Applicant	Class	Sub-class
	US-4,782,028	11-01-1988	Farrier et al.	437	003
	US-5,137,837	08-11-1992	Chang et al.	437	021
	US-5,807,771	09-15-1998	Vu et al.	438	154
	US-6,072,224	06-06-2000	Tyson et al.	257	443
	US-6,617,646 B2	09-09-2003	Parab	257	347
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FOREIGN PATENT DOCUMENTS

Examiner Initials	Document Number (Country Code-Number-Kind Code)	Publication Date (MM-DD-YYYY)	Name Of Patentee of Applicant	Translation? Yes/No/n/a
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OTHER DOCUMENTS (Author (Capitalize), Title, Date, Pages, Etc., if known)

	F. FOULON, L.ROUSSEAU, L.BABADJIAN, S.SPIRKOVITCH, A.BRAMBILLA and P.BERGONZO, "A New Technique for the Fabrication of Thin Silicon Radiation Detectors", pgs. 218-220, IEEE Transactions on Nuclear Science, Vol. 46, No. 3, June 1999,

Examiner's Signature:

Date Considered:

Initial if reference was considered, whether or not citation is in conformance with MPEP. Mark through citation if not considered.
Include a copy of this citation form with your next correspondence to the Applicant(s).